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The NaI:Tl and CsI:Tl crystals for effective detection of X-rays and low energy charged particles

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DAMA single detector unit



Design like DAMA II stage.... Why not think about how to improve it?

In DAMA/SABRE experiments expected energy range is 2-4 keV



See Talk by E. Shields at TAUP2013

Internal Source: 0.84 keV

McCann M.F. and Smith K.M. On the Detection of 1 keV Events in NaI:Tl NIM, 65 (1968) 173.

Characteristic X-rays



Problems of low energy particle detection

Light yield depends on dE/dx

Energy resolution and non-proportionality of response

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Dark matter search with NaI and CsI



Quenching factor for ²³Na and ¹²⁷J

Protons	100 %	
Alphas	60 %	
²⁰ Ne	42 %	
it can be estimated		
²³ Na	$\sim 35\%$	
^{127}I	$\sim 8 \%$	

Quenching factor depends on Tl concentration

Optimum Tl concentration (C_{Tl}^*) in NaI:Tl



 $C_{\text{Tl}}^* = 7.3 \cdot 10^{-2} \%$ for soft X-rays of 5.9 keV;

 $C_{\text{Tl}}^* = 1.3 \cdot 10^{-1} \%$ for α -particles.

Requirements to scintillation material for charged particles and light ions detection:

- maximum scintillation efficiency to photons detection;
- high transparency to rich maximum light collection coefficient;
- homogeneity of thallium distribution and other dopands to rich best value of energy resolution;

Additional:

- increased Tl concentration to rich best scintillation efficiency for charged particles detection;
- stability of surface state;
- absence of dead layer.

$C_{\text{Tl}}^* > 0.15$ % for ion detection in NaI:T1

NaI:Tl crystal for particle detection: homogeneity

Furnace for crystal growth with conical crucible "Crystal-400"







Distribution of Tl and other coactivators in scintillation material "CsI:Tl,Na,CO₃" along height. The same is thru for NaI:Tl

Impurity distribution in crystal grown by Bridgman-Stockbarger technique

 $C_{\text{Tl}} = C_0 k_0 \left(1 - \frac{V}{V_o}\right)^{k_0 - 1}$ k_o – equilibrium segregation coefficient $C_{\mathrm{TI}} [\mathrm{mm}]$ NaI:Tl 1 - crystal growth invacuum; 28 2 - crystal growth in 1 0 24 oxygen; 3 – calculated curve for 2 20 $k_0 = 0.25$ 3 $C_0 = 0.36 \%$ 2 16 . 12 20 0 40 60 80 100 h [mm]

In heavy doped crystal activator is distributed non-uniformly

Non-homogeneous distribution of activator in CsI:Tl (microscopic)



Table: PIXE analysis results

Brand	CsI	Nominal TI	Measured Tl	Type of
	n.	conc.(ppm)	conc. (ppm)	measure
GB	1	4000	6400±200	Face A, av
GB	1	4000	9300±300	Face A, point
GB	1	4000	5400±200	Face A, point
GB	1	4000	6100±200	Face B, av
GB	1	4000	4610 ± 180	Side, av
GB	2	3000	2950±110	Face A, av
GB	2	3000	4900±200	Face B, point
GB	2	3000	3030±120	Face B, av
St. Gobain	- 3	500	440 ± 50	Face A, av
St. Gobain	4	200	280±30	Face A, av
Marketech	5	700	520±30	Face A, av
Scionix	6	2500	5220±160	Face A, av

FAZIA collaboration results

In $C_{Tl} > 0.2\%$ the activator is not homogeneous distributed both macroscopically and microscopically

Nature of concentration quenching



Schematic image of microscopic distribution of Tl⁺ center in CsI crystal at high Tl concentration. Photo represents the character of decoration of the cleavage plane in two different places. (Electron microscope; ×16 000; decoration by gold). Black squares correspond to places of increased Tl content (so-called spinodal decay of solid solution)

Uniformity of spectrometric parameters

Photodiode scintillator of 200 cm³ volume. 16 sample from selected region of ingot.

CsI:Tl ingot of 240 mm dia. and 360 mm heigh

Pulse height spectra for each element (left) and summarized spectrum of whole block (right).

V = 216 cm³.









Nature of millisecond afterglow





Nature of millisecond afterglow



Oxygen suppress AG and LY



Nature of millisecond afterglow and its suppressing



 $TI^+ - O_2^- - TI^+$



Model of electron trap which forms a quenching center for recombination luminescence

Crystal growth of uniform and heavy-activated ingot





Scintillation materials: CsI:Tl,CO₃ or NaI:Tl,CO₃



Conclusion

- for Dark Matter search the heavy doped NaI:TI crystals are needed;
- characterization of crystal quality should be done using alphaparticles and fissing fragments;
- it has been shown that NaI:TI crystals with $C_{TI} \sim 0.3$ % are available (so called NaI:TI,IO₃ crystals). CsI:TI,IO₃ crystals with $C_{TI} \sim 0.5$ % can be grown by Stockbarger technique;
- uniformity of NaI:TI,IO₃ and CsI:TI,IO₃ ingots is bad due to used crystallization technique;
- to obtain large uniform NaI:TI crystal the modified Kyropoulos technique should be used;
- to obtain large heavy doped NaI:TI crystal we recommend NaI:TI,NO₂ scintillation material for crystal growth.

Concentration dependences of light yield





Density of *e-h* pair in electron track:

$$\begin{cases} 2.2 \cdot 10^{18} \text{cm}^{-3} \text{ for } 662 \text{ keV } (1, \gamma) \\ 7.3 \cdot 10^{18} \text{ cm}^{-3} \text{ for } 5.9 \text{ keV } (2) \\ 1,3 \cdot 10^{19} \text{ cm}^{-3} \text{ for } \alpha (5,15 \text{ MeV}) \end{cases}$$

Volume density *dE/dx*³ is increased 3 times in L-deep

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